

## NCE Automotive N-Channel **Super Trench II** Power MOSFET

### Description

The series of devices uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

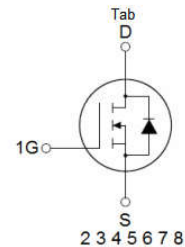
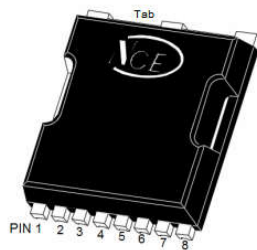
### Application

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

### General Features

- $V_{DS} = 100V, I_D = 385A$   
 $R_{DS(ON)} = 1.2m\Omega$ , typical@  $V_{GS} = 10V$
- Excellent gate charge x  $R_{DS(on)}$  product(FOM)
- Very low on-resistance  $R_{DS(on)}$
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100%  $\Delta V_{ds}$  tested
- **AEC-Q101 qualified**

**TOLL-8L**



**Schematic Diagram**

### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP016N10LL	NCEAP016N10LL	TOLL-8L	-	-	-

### Absolute Maximum Ratings ( $T_c = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	100	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$I_D (T_c = 25^\circ C)$	385	A
	$I_D (T_c = 100^\circ C)$	280	A
Pulsed Drain Current	$I_{DM}$	1540	A
Maximum Power Dissipation	$P_D$	500	W
Derating factor		3.3	W/°C
Single pulse avalanche energy (Note 1)	$E_{AS}$	3175	mJ
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 175	°C

### Thermal Characteristic

Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.3	°C/W
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**Electrical Characteristics (T<sub>c</sub>=25°C unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	1.2	1.6	mΩ
Gate resistance	R <sub>G</sub>	F=1.0MHz	-	2.5	-	Ω
Forward Transconductance	g <sub>FS</sub>	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	-	120	-	S
Dynamic Characteristics						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V, F=1.0MHz	-	23100	-	pF
Output Capacitance	C <sub>OSS</sub>		-	1850	-	pF
Reverse Transfer Capacitance	C <sub>rSS</sub>		-	100	-	pF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =50V,I <sub>D</sub> =20A V <sub>GS</sub> =10V,R <sub>G</sub> =1.6Ω	-	40	-	nS
Turn-on Rise Time	t <sub>r</sub>		-	32	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	100	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	36	-	nS
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =50V,I <sub>D</sub> =20A, V <sub>GS</sub> =10V	-	285	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	85	-	nC
Gate-Drain Charge	Q <sub>gd</sub>		-	72	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Diode Forward Current	I <sub>S</sub>		-	-	385	A
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> = 20A	-	110	-	nS
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 100A/μs	-	300	-	nC

**Notes:**

1. EAS condition : T<sub>J</sub>=25°C, V<sub>DD</sub>=50V, V<sub>G</sub>=10V, L=0.5mH, R<sub>G</sub>=25Ω
2. Guaranteed by design, not subject to production
3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T<sub>J(MAX)</sub>=175°C. The SOA curve provides a single pulse rating.

## Typical Electrical and Thermal Characteristics

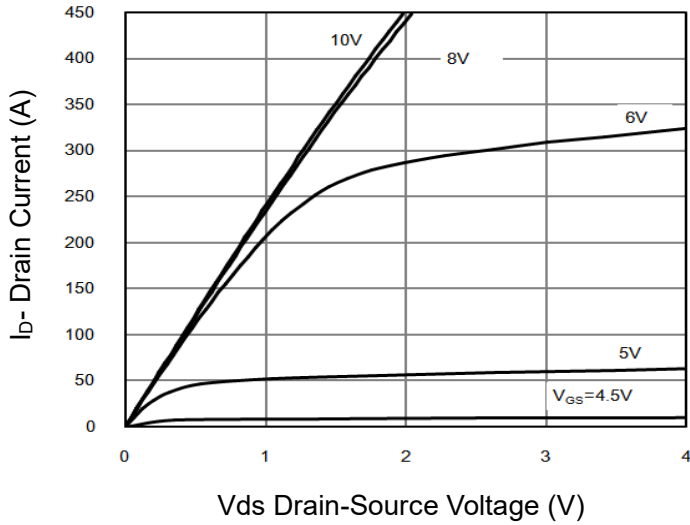


Figure 1 Output Characteristics

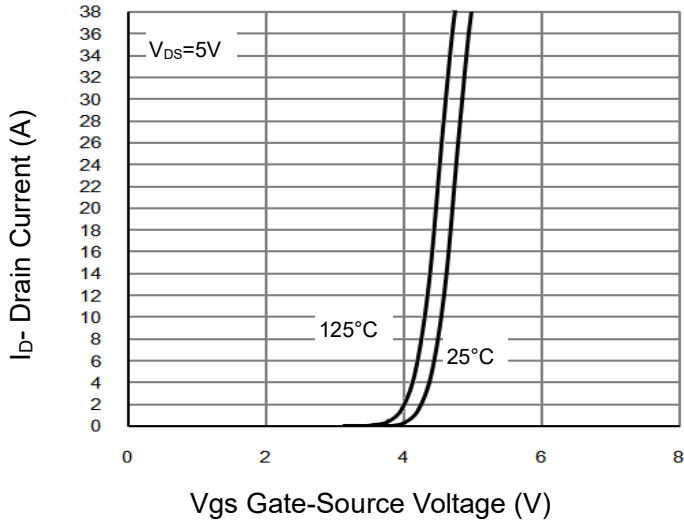


Figure 2 Transfer Characteristics

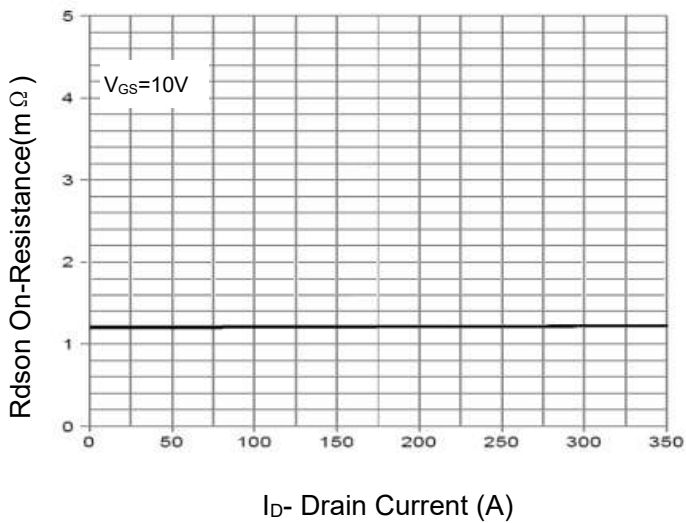


Figure 3  $R_{DS(on)}$ - Drain Current

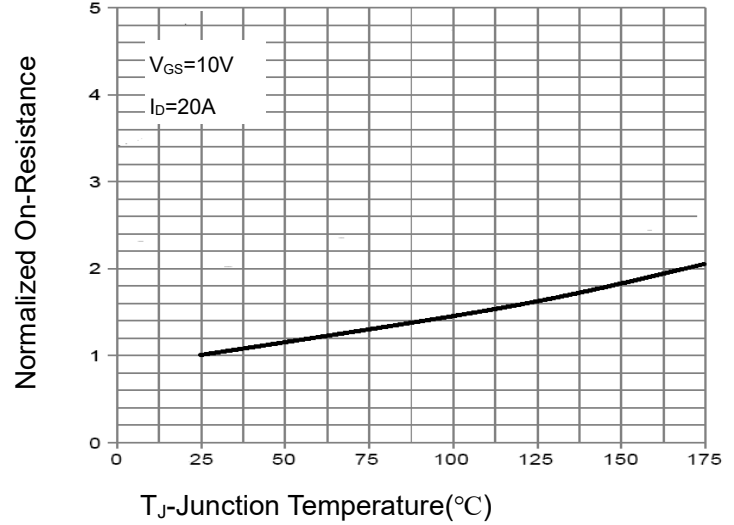


Figure 4  $R_{DS(on)}$ -Junction Temperature

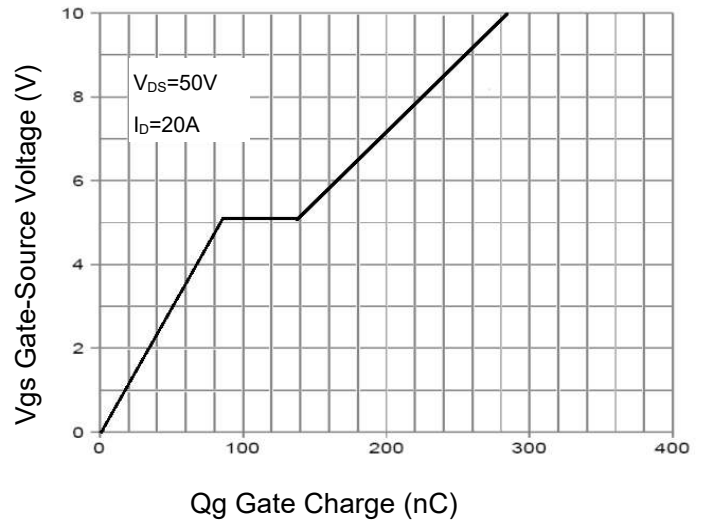


Figure 5 Gate Charge

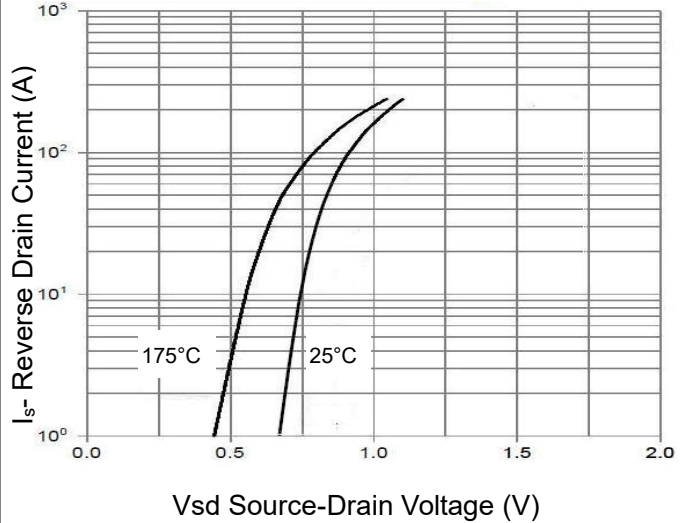
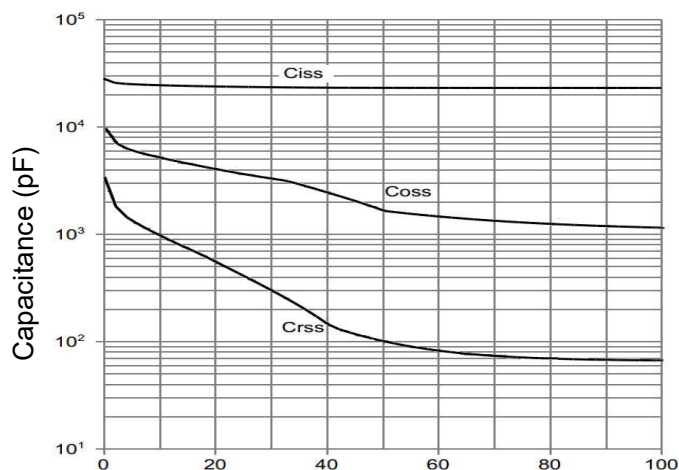
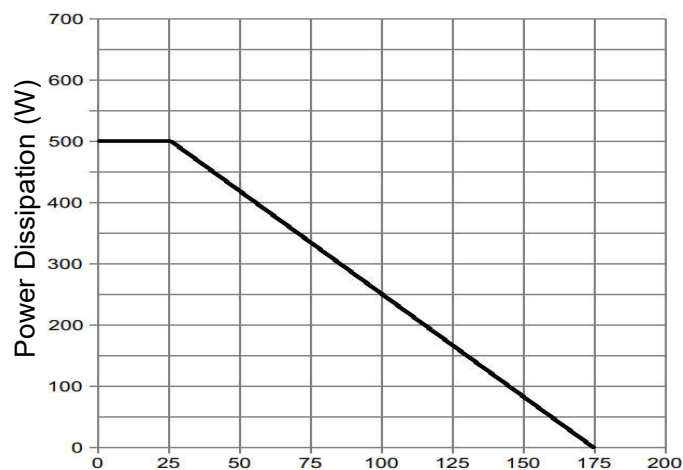


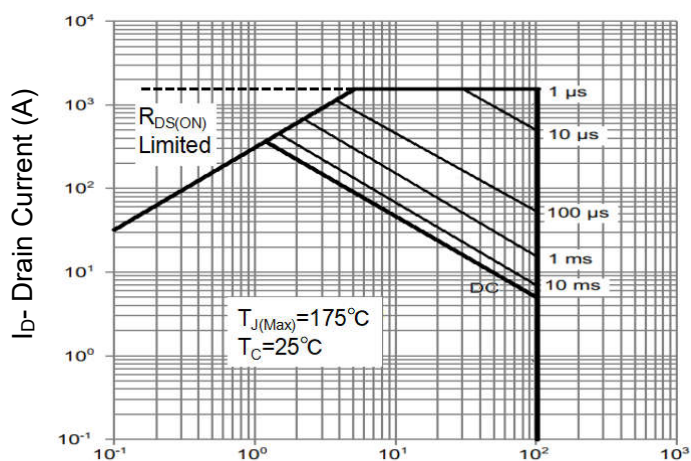
Figure 6 Source- Drain Diode Forward



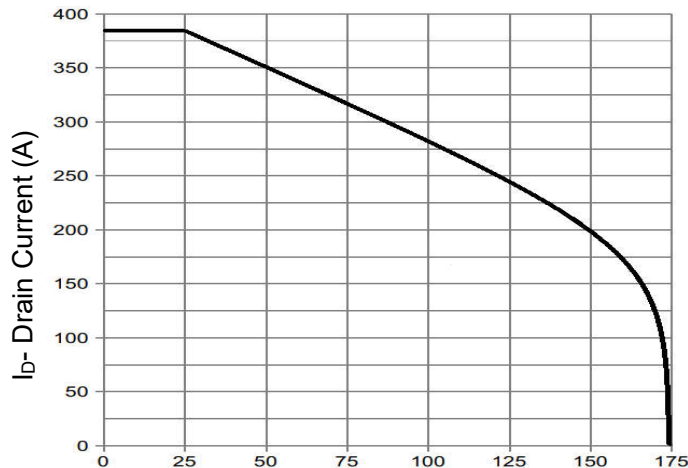
Vds Drain-Source Voltage (V)  
**Figure 7 Capacitance vs Vds**



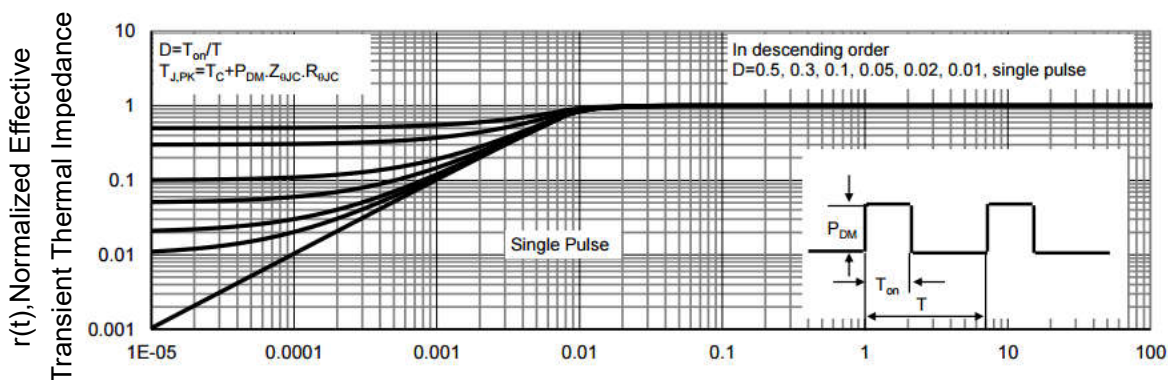
T<sub>C</sub>-Case Temperature(°C)  
**Figure 9 Power De-rating**



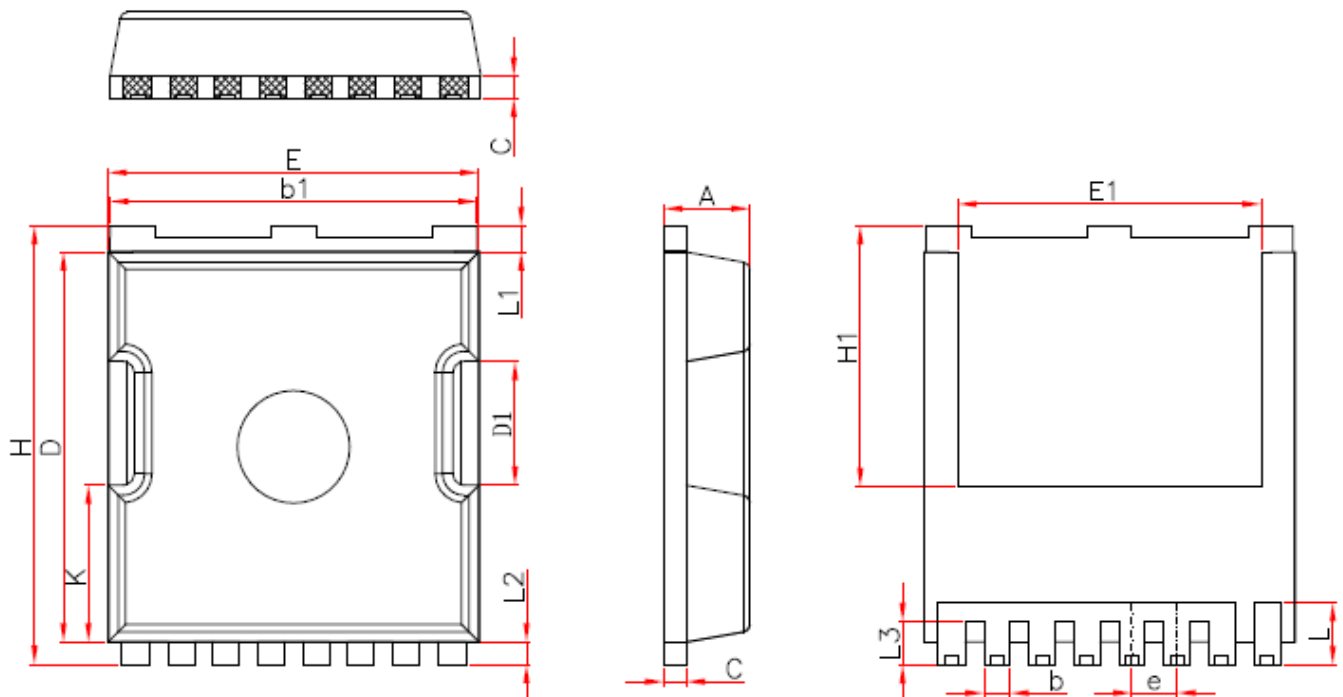
Vds Drain-Source Voltage (V)  
**Figure 8 Safe Operation Area** (Note3)



T<sub>C</sub>-Case Temperature (°C)  
**Figure 10 Current De-rating**



Square Wave Pulse Duration(sec)  
**Figure 11 Normalized Maximum Transient Thermal Impedance**

**TOLL Package Information**


Symbol	Millimeters		
	Min.	Nom.	Max.
A	2.20	2.30	2.40
b	0.65	0.75	0.85
b1	9.70	9.80	9.90
C	0.50	0.60	0.70
D	10.30	10.40	10.50
D1	3.15	3.3	3.45
E	9.70	9.90	10.10
E1	8.00	8.10	8.20
e	1.10	1.20	1.30
H	11.6	11.7	11.8
H1	6.85	6.95	7.05
K	4.08	4.18	4.28
L	1.60	1.65	2.10
L1	0.60	0.70	0.80
L2	0.50	0.60	0.70
L3	1.05	1.20	1.30

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